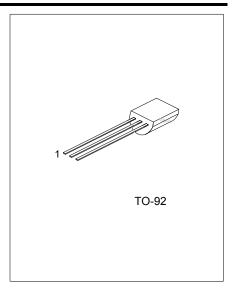
2N7000Z Power MOSFET

115m Amps, 60 Volts N-CHANNEL ENHANCEMENT **MODE MOSFET**

DESCRIPTION

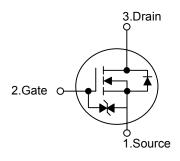
The UTC 2N7000Z has been designed to minimize on-state resistance to provide rugged, reliable, and fast switching performance. It can be used in most applications requiring up to 400mA DC and can deliver pulsed currents up to 2A. The product is particularly suited for low voltage, low current applications, such as small servo motor control, power MOSFET gate drivers and other switching applications



FEATURES

- *High density cell design for low R_{DS(ON)}
- *Voltage controlled small signal switch
- *Rugged and reliable
- asheet.Live *High saturation current capability

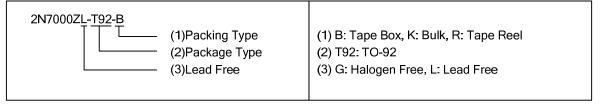
SYMBOL



ORDERING INFORMATION

Ordering Number		Dookogo	Pin Assignment			Dooking	
Lead Free	Halogen Free	Package	1	2	3	Packing	
2N7000ZL-T92-B	2N7000ZG-T92-B	TO-92	S	G	D	Tape Box	
2N7000ZL-T92-K	2N7000ZG-T92-K	TO-92	S	G	D	Bulk	
2N7000ZL-T92-R	2N7000ZG-T92-R	TO-92	S	G	D	Tape Reel	

Note: Pin Assignment: G: Gate D: Drain S: Source



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■ ABSOLUTE MAXIMUM RATINGS (Ta=25°C)

PARAMETER		SYMBOL RATINGS		UNIT
Drain-Source Voltage		V_{DSS}	60	V
Drain-Gate Voltage (R _{GS} ≤1MΩ)		V_{DGR}	60	V
Gate -Source Voltage	Continuous	V _{GS}	±20	V
	Non Repetitive (tp<50μs)		±40	V
Maximum Drain Current Continuous		l _o	115	mA
Maximum Brain Current	Pulsed	- I _D	800	mA
Maximum Power Dissipation		PD	400	mW
Derated above 25°C		FD	3.2	mW/°C
Operating and Storage Temperature		$T_{J,}T_{STG}$	-55 ~ +150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ THERMAL DATA

PARAMETER	SYMBOL	RATINGS	UNIT
Junction to Ambient	$\theta_{\sf JA}$	312.5	°C/W

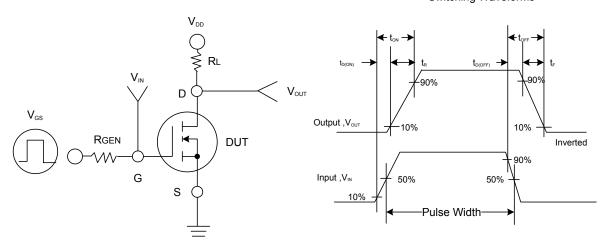
■ **ELECTRICAL CHARACTERISTICS** (Ta =25°C, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
OFF CHARACTERISTICS					_	
Drain-Source Breakdown Voltage	BV _{DSS}	V_{GS} =0 V , I_D =10 μ A	60			V
Drain-Source Leakage Current	I _{DSS}	V _{DS} =60V, V _{GS} =0V T _J =125°C			1 0.5	μA mA
Gate-Body leakage, Forward	I _{GSSF}	V _{GS} =20V, V _{DS} =0V			10	μA
Gate-Body leakage Reverse	I _{GSSR}	V _{GS} =-20V, V _{DS} =0V			-10	μA
ON CHARACTERISTICS (Note)	100011	1.00 =11, 120 11		1		P
Gate Threshold Voltage	V _{GS(TH)}	V _{DS} =V _{GS} , I _D =250μA	1	2.1	2.5	V
Static Drain-Source On-Resistance	R _{DS(ON)}	V _{GS} =10V, I _D =500mA T _J =100°C V _{GS} =5.0V, I _D =50mA T _J =100°C		1.2 1.7 1.7 2.4	7.5 13.5 7.5 13.5	Ω
Drain-Source On-Voltage	V _{DS(ON)}	V_{GS} = 10V, I_D =500mA V_{GS} = 5.0V, I_D =50mA		0.6 0.09	3.75 1.5	V
On-State Drain Current	I _{D(ON)}	$V_{GS}=10V, V_{DS} \ge 2V_{DS(ON)}$	500	2700		mA
DYNAMIC CHARACTERISTICS	. , ,				I	
Input Capacitance	C _{ISS}			20	50	pF
Output Capacitance	Coss	V _{DS} =25V,V _{GS} =0V, f=1.0MHz		11	25	pF
Reverse Transfer Capacitance	C _{RSS}	1		4	5	pF
Turn-On Time	t _{ON}	V_{DD} =30V, R_L =150 Ω , I_D =200mA, V_{GS} =10V, R_{GEN} =25 Ω			20	ns
Turn-Off Time	toff	V_{DD} =30V, R_L =150 Ω , I_D =200mA, V_{GS} =10V, R_{GEN} =25 Ω			20	ns
DRAIN-SOURCE DIODE CHARACT	ERISTICS A	AND MAXIMUM RATINGS				
Drain-Source Diode Forward Voltage	V _{SD}	V _{GS} =0V, Is=115mA(Note)		0.88	1.5	V
Maximum Continuous Drain-Source Diode Forward Current	Is				115	mA
Maximum Pulsed Drain-Source Diode Forward Current	I _{SM}				0.8	Α

Note: Pulse Test: Pulse Width≤300µs, Duty Cycle≤2.0%

■ TYPICAL CHARACTERISTICS

Switching Waveforms



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